

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	1	memory same string same sense same detect same (voltage or potential or bias) same time same second same write same (comapre or comparing) same logic	US-PGPUB; USPAT; EPO; JPO
2	BRS	L2	3	memory same string same sense same detect same (voltage or potential or bias) same time same second and write and (comapre or comparing) and logic	US-PGPUB; USPAT; EPO; JPO
3	BRS	L3	3	memory same string same sense same detect same (voltage or potential or bias) and time and second and write and (comapre or comparing) and logic	US-PGPUB; USPAT; EPO; JPO
4	BRS	L4	3	memory same string same sense same detect and (voltage or potential or bias) and time and second and write and (comapre or comparing) and logic	US-PGPUB; USPAT; EPO; JPO
5	BRS	L5	50	memory same string same sense and detect and (voltage or potential or bias) and time and second and write and (comapre or comparing) and logic	US-PGPUB; USPAT; EPO; JPO
6	BRS	L6	29	memory same string same detect and sense and (voltage or potential or bias) and time and second and write and (comapre or comparing) and logic	US-PGPUB; USPAT; EPO; JPO
7	BRS	L7	3026	memory same detect and sense and (voltage or potential or bias) and time and second and write and (comapre or comparing) and logic	US-PGPUB; USPAT; EPO; JPO
8	BRS	L8	2	memory same sense same detect same (voltage or potential or bias) same time same second same write same (comapre or comparing) same logic	US-PGPUB; USPAT; EPO; JPO